

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S41	305	(naoyuki near2 takahashi or takato near2 nakamura or satoshi near2 nonaka or yoichi near2 shinriki or katsumi near2 tamanuki).in.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/29 17:50
S42	13	(naoyuki near2 takahashi or takato near2 nakamura or satoshi near2 nonaka or yoichi near2 shinriki or katsumi near2 tamanuki).in. and quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/29 17:58
S43	2	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane) same epitax\$6 near10 quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/29 17:54
S44	13	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane) same epitax\$6 near10 (silicon near2 (oxide or dioxide) or "sio.sub.2")	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/29 17:56
S45	220	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane) same quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/29 17:56
S46	68	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane) near15 quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/29 17:56
S47	1	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane) near15 quartz same (hcl or chloride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/29 17:56
S48	324	epitax\$6 near5 quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/29 17:58
S49	79	epitax\$6 near5 quartz near2 (film or layer)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 12:57

S50	179	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:02
S51	0	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 silica near10 epitax\$6	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 12:58
S52	3073	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 silica	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 12:58
S53	32	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 silica near10 crystal\$7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 12:58
S54	3	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 (quartz or silica or "sio.sub.2" or silicon near2 (oxide or dioxide)) near10 epitax\$7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:02
S55	19	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) same (quartz or silica or "sio.sub.2" or silicon near2 (oxide or dioxide)) near10 epitax\$7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:06
S56	2428	quartz near15 (cvd or chemical near2 vapor near2 deposit\$6 or pecvd)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:06
S57	10	quartz near15 (cvd or chemical near2 vapor near2 deposit\$6 or pecvd) same (tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:31
S58	28	quartz near15 (cvd or chemical near2 vapor near2 deposit\$6 or pecvd) same (hcl or chloride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:31

S59	742	lattice near2 constant near5 (gan or gallium near2 nitride)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:58
S60	125	lattice near2 constant near5 (zno or zinc near2 oxide)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:59
S61	20	lattice near2 constant near5 (quartz)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/12/30 13:59
S62	49	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) and (single adj crystal or epitax\$3) near10 catalyst	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:11
S63	75	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 catalyst and (single adj crystal or epitax\$3)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:14
S64	408	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 catalyst near10 (chloride or hcl or halogen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:14
S65	8	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 catalyst near10 (chloride or hcl or halogen) same (crystal\$6 or epitax\$6)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:15
S66	194	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 catalyst near10 (hydrogen near2 chloride or hcl or halogen)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:15
S67	0	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 catalyst near10 (hydrogen near2 chloride or hcl or halogen) near15 quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:15

S68	1	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) near10 catalyst near10 (hydrogen near2 chloride or hcl or halogen) same quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:16
S69	10	(tetramethoxysilane or tetraethoxysilane or tetrapropoxysilane or tetrabutoxysilane or alkoxide) and catalyst near10 (hydrogen near2 chloride or hcl or halogen) same quartz	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/01/03 14:16